## FAIRCHILD

SEMICONDUCTOR®

# FDP8441\_F085

# N-Channel PowerTrench<sup>®</sup> MOSFET 40V, 80A, 2.7m $\Omega$

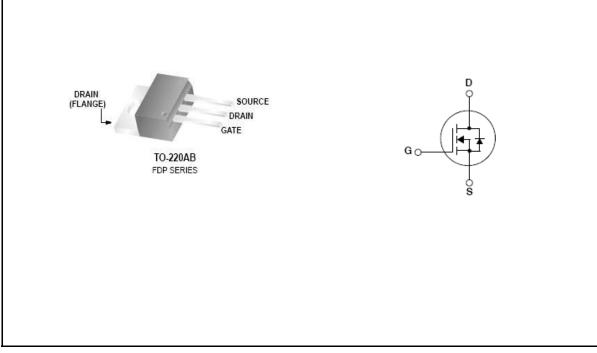
#### **Features**

- Typ  $r_{DS(on)} = 2.1 m\Omega$  at  $V_{GS} = 10V$ ,  $I_D = 80A$
- Typ Q<sub>g(10)</sub> = 215nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

# AD FREE HURLING

# Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems



May 2010

www.fairchildsemi.com

Symbol	Parameter		Ratings	Units
V <sub>DS</sub>	Drain to Source Voltage		40	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
	Drain Current Continuous (T <sub>C</sub> < 160°C, V <sub>GS</sub> = 10V)		80	
I <sub>D</sub>	Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 62°C/W)		23	Α
	Pulsed		See Figure 4	
E <sub>AS</sub>	Single Pulse Avalanche Energy (N	Note 1)	947	mJ
	Power dissipation		300	W
P <sub>D</sub>	Derate above 25°C		2	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to 175	°C

### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.5	5	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient (No	ote 2) 62		°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP8441	FDP8441_F085	TO-220AB	Tube	N/A	50 units

# **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

Symbol Parameter Test Conditions Min Typ Max Unit							
Symbol Fuldineter Feet Conditions Mini Typ Max Onit	Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

#### **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{C}$	$I_{D} = 250 \mu A, V_{GS} = 0V$		-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 32V$		-	-	1	μA
DSS	Zero Gale Vollage Drain Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C$	-	-	250	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

#### **On Characteristics**

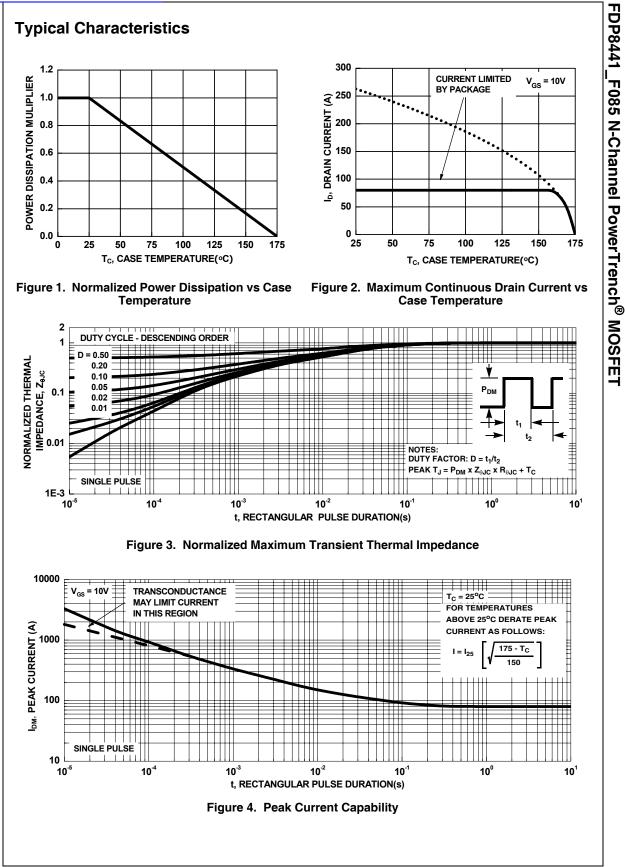
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	2.8	4	V
		I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V	-	2.1	2.7	
r <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, T <sub>J</sub> = 175°C	-	3.6	4.7	mΩ

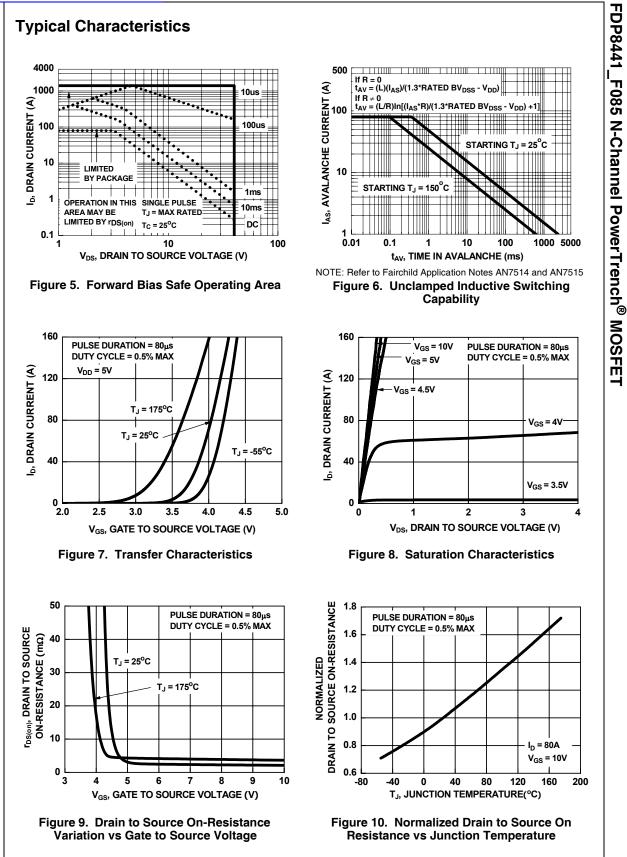
#### **Dynamic Characteristics**

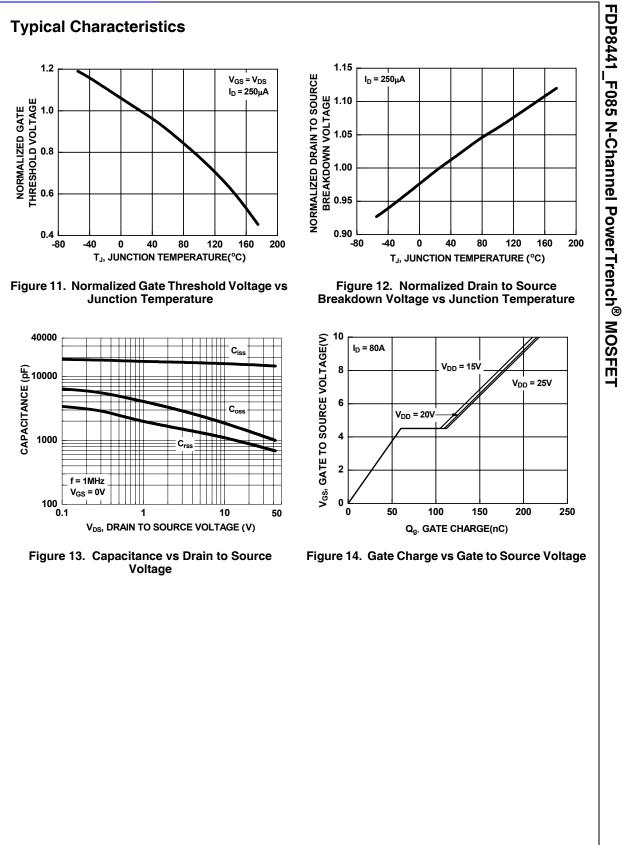
C <sub>iss</sub>	Input Capacitance		0)/	-	15000	-	pF
C <sub>oss</sub>	Output Capacitance	──V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, ──f = 1MHz		-	1250	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	685	-	pF
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> = 0.5V, f = 1	MHz	-	1.1	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	215	280	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0$ to 2V	V <sub>DD</sub> = 20V	-	29	38	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 35A	-	60	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau		l <sub>g</sub> = 1mA	-	32	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	49	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switchin	g Characteristics					
(on)	Turn-On Time		-	-	77	ns
d(on)	Turn-On Delay Time		-	23	-	ns
r	Turn-On Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 35A	-	24	-	ns
d(off)	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 1.5\Omega$	-	75	-	ns
·a(off)		VGS = 10V, HGS = 1.322				
	Turn-Off Fall Time		-	17.9	-	ns
f off	Turn-Off Fall Time Turn-Off Time		-	17.9 -	- 147	ns ns
r Orain-So	Turn-Off Time	I <sub>SD</sub> = 35A	-		- 147 1.25	
f off	Turn-Off Time	I <sub>SD</sub> = 35A I <sub>SD</sub> = 15A	-	-		ns
r Orain-So	Turn-Off Time	I <sub>SD</sub> = 35A I <sub>SD</sub> = 15A I <sub>F</sub> = 35A, di/dt = 100A/μs	-	- 0.8	1.25	ns V

`	/	Source to Drain Diode Voltage	I <sub>SD</sub> = 35A	-	0.8	1.25	V
ľ	/ <sub>SD</sub>	Source to Drain Diode voltage	I <sub>SD</sub> = 15A	-	0.8	1.0	V
t	rr	Reverse Recovery Time	I <sub>F</sub> = 35A, di/dt = 100A/μs	-	52	68	ns
C	ל <sup>ער</sup>	Reverse Recovery Charge	$I_F = 35A$ , di/dt = 100A/µs	-	76	99	nC







#### 查询"FDP8441\_F005"供应商 FAIRCHILD

SEMICONDUCTOR

#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ Auto-SPM™ Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTL™ Current Transfer Logic™ DEUXPEED® Dual Cool™ EcoSPARK<sup>®</sup> EfficientMax™ ESBC™ F R Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT<sup>®</sup> FAST<sup>®</sup> FastvCore™ FETBench™ FlashWriter®\*

F-PFS™ **FRFET**<sup>®</sup> Global Power Resource SM Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ **ISOPLANAR™** MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Motion-SPM™ OptoHiT™ **OPTOLOGIC<sup>®</sup> OPTOPLANAR®** PDP SPM™

Power-SPM™ PowerTrench® PowerXS™ Programmable Active Droop™ OFFT QS™ Quiet Series™ RapidConfigure™ )™ Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ SPM® STEALTH™ SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™

# The Power Franchise<sup>®</sup>

p franchise

TinyBoost™ TinyBoost™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™\* µSerDes™



UHC<sup>™</sup> Ultra FRFET<sup>™</sup> UniFET<sup>™</sup> VCX<sup>™</sup> VisualMax<sup>™</sup> XS<sup>™</sup>

\* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

**FPSTM** 

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

SyncFET™

Sync-Lock™

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

- Life support devices or systems are devices or systems which, (a) are
  intended for surgical implant into the body or (b) support or sustain life,
  and (c) whose failure to perform when properly used in accordance
  with instructions for use provided in the labeling, can be reasonably
  expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and vartantizes and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information Formative / In Design		Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.